DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

DB151 THRU DB157

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts *CURRENT - 1.5 Ampere*

FEATURES

* Good for automation insertion
* Surge overload rating - 50 Amperes peak
* Ideal for printed circuit board
* Reliable low cost construction
* Glass passivated junction

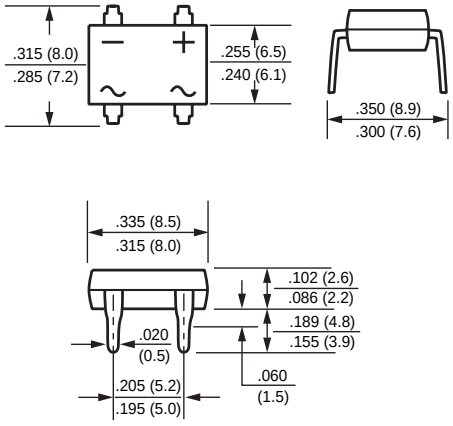
MECHANICAL DATA

* Case: Molded plastic
* Epoxy: UL 94V-0 rate flame retardant
* Lead: MIL-STD-202E, Method 208 guaranteed
* Polarity: Symbols molded or marked on body
* Mounting position: Any
* Weight: 0.4 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

DB-1



Dimensions in inches and (millimeters)

		SYMBOL	DB151	DB152	DB153	DB154	DB155	DB156	DB157	UNITS
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at T_A = 40°C		I_O	1.5							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I_{FSM}	60							Amps
Maximum Forward Voltage Drop per element at 1.0A DC		V_F	1.1							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage per element	@T_A = 25°C	I_R	10							uAmps
	@T_A = 125°C		500							
I^2t Rating for Fusing (t<8.3ms)		I^2t	10							A^2Sec
Typical Junction Capacitance (Note1)		C_J	25							pF
Typical Thermal Resistance (Note 2)		$R\theta JA$	40							°C/W
Operating and Storage Temperature Range		$T_{J,TSTG}$	-65 to + 150							°C

NOTES : 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B. with 0.5 x 0.5" (13x13mm) copper pads.